



TELEFUNKEN electronic
Creative Technologies

Silicon Photo PIN Diode (N-Type)

in clear plastic package for plastic fiber connection

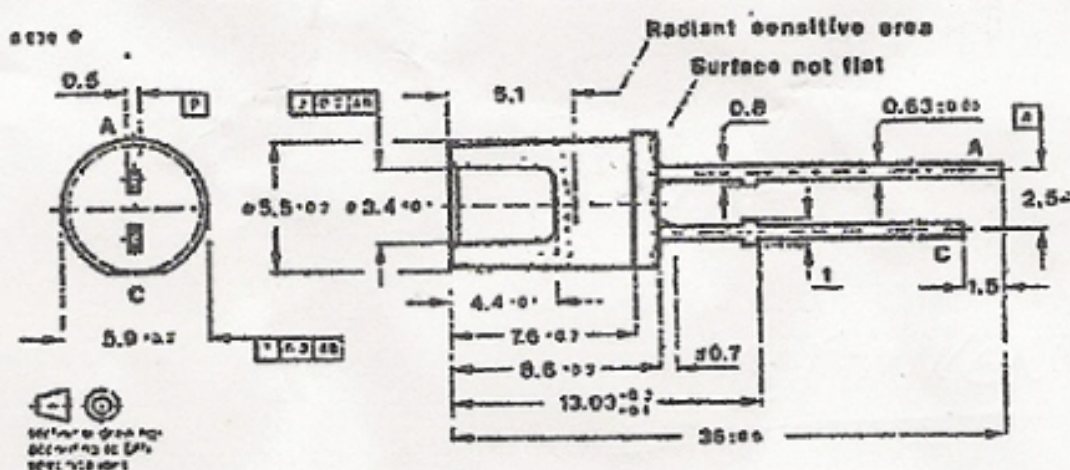
Applications: Signal receiver for:

- Low cost fiber links
- Large distance isolators
- Special interrupters

Features:

- Suitable for large range of wavelength
- High coupling efficiency for \varnothing 1 mm plastic fibers
- With special accessories usable for three different diameters of plastic fiber
- Compatible to TLY. 5200 series and TLYR 5500

Dimensions in mm



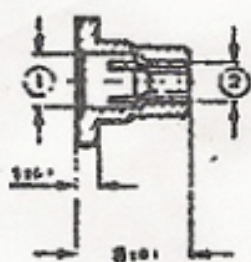
Accessories:

Clips for coupling with plastic fiber

Type	Fiber diameter mm	Dimensions in mm for:	
		①	②
YC 10	1.0	1.1	0.8
YC 15	1.5	1.65	1.3
YC 20	2.0	2.2	1.7

Special case

Weight max. 0.4 g



TEYD 5500

T-41-53

Absolute maximum ratings

Reverse voltage	V_R	32	V
Power dissipation $T_{amb} \leq 25^\circ\text{C}$	P_V	210	mW
Junction temperature	T_j	100	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 ... +100	$^\circ\text{C}$
Soldering temperature $t \leq 5\text{ s}$	T_{sd}	260	$^\circ\text{C}$

Thermal resistance

		Min.	Typ.	Max.	
Junction ambient	R_{thJA}			350	K/W

Optical and electrical characteristics

$T_{amb} = 25^\circ\text{C}$					
Forward voltage $I_F = 50\text{ mA}$	V_F		0.9	1.2	V
Breakdown voltage $I_R = 100\ \mu\text{A}, E = 0$	$V_{(BR)}$	32			V
Reverse dark current $V_R = 10\text{ V}, E = 0$	I_{ro}		2	10	nA
Light reverse current $V_R = 5\text{ V}, E_o = 1\text{ mW/cm}^2$					
$\lambda = 660\text{ nm}$	I_{ro}	4.0	5.5		μA
$\lambda = 870\text{ nm}$	I_{ro}		7		μA
Temperature coefficient	TKI_{ro}		< +0.2		%/K
Absolute spectral sensitivity $V_R = 5\text{ V}, \lambda = 660\text{ nm}$	$s(\lambda)$		0.45		A/W
$V_R = 5\text{ V}, \lambda = 870\text{ nm}$	$s(\lambda)$		0.60		A/W
Peak wavelength sensitivity	λ_p		930		nm
Range of spectral bandwidth	$\lambda_{0.5}$		600...1050		nm
Dark resistance $V_R = 10\text{ mV}, E = 0, f = 0$	R_D		1		G Ω
Junction capacitance $V_R = 3\text{ V}, f = 1\text{ MHz}$	C_j		4		pF

Switching characteristics

 $V_R = 10\text{ V}, R = 50\ \Omega, \lambda = 820\text{ nm}$

Rise time	t_r	12	ns
Fall time	t_f	12	ns
Cut - off frequency $\lambda = 660\text{ nm}$	f_o	200	MHz